



EPC2101ENG Information

Part Number EPC2101ENG

Manufacturer EPC

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Arrays

Description TRANS GAN 2N-CH 60V BUMPED DIE

Package Die

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

For Reference Only

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









EPC2101ENG Specifications

	Report errors?
Supplier Device Package	Die
Package / Case	Die
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 150°C (TJ)
Power - Max	-
Input Capacitance (Ciss) (Max) @ Vds	300pF @ 30V
Gate Charge (Qg) (Max) @ Vgs	2.7nC @ 5V
Vgs(th) (Max) @ Id	2.5V @ 2mA
Rds On (Max) @ Id, Vgs	11.5 mOhm @ 20A, 5V
Current - Continuous Drain (Id) @ 25°C	9.5A, 38A
Drain to Source Voltage (Vdss)	60V
FET Feature	GaNFET (Gallium Nitride)
FET Type	2 N-Channel (Half Bridge)
Series	eGaN?
Package	Die
	Transistors - FETs, MOSFETs - Arrays
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Manufacturer	EPC
Manufacturer Part Number	EPC2101ENG

EPC2101ENG Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

EPC2101ENG Payment Methods





















EPC2101ENG Shipping Methods













If you have any question about EPC2101ENG, please do not hesitate to contact us!

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